



DMP31D0U

Product Summary

| BV _{DSS} | Max R _{DS(ON)} | Max I _D @ T _A = 25°C |
|-------------------|--------------------------------|--|
| | 1Ω @ V _{GS} = -4.5V | -0.67A |
| -30V | 1.5Ω @ V _{GS} = -2.5V | -0.54A |
| | 2Ω @ V _{GS} = -1.8V | -0.47A |

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$, yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Load Switch in Portable Electronics

30V P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

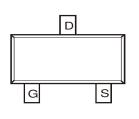
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (€3)
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)





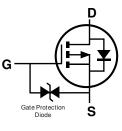
SOT23

Top View



Top View

Internal Schematic



Equivalent Circuit

Ordering Information (Note 4)

| Part Number | Case | Packaging |
|-------------|-------|-------------------|
| DMP31D0U-7 | SOT23 | 3,000/Tape & Reel |

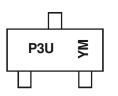
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



P3U = Product Type Marking Code YM = Date Code Marking Y = Year (ex: Y = 2011) M = Month (ex: 9 = September)

| Date Code Kev | |
|---------------|--|

| Year | 2011 | ~ | 2016 | 20 | 17 | 2018 | 2019 | 2020 | 202 | 21 | 2022 | 2023 |
|-------|------|-----|------|-----|-----|------|------|------|-----|-----|------|------|
| Code | Y | ~ | D | F | | F | G | H | 1 | | J | K |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Cha | aracteristic | | Symbol | Value | Unit |
|-------------------------------|-----------------|---|------------------|-------------------------|------|
| Drain-Source Voltage | | | V _{DSS} | -30 | V |
| Gate-Source Voltage | | | V _{GSS} | ±8 | V |
| Continuous Drain Current | Steady State | $T_A = +25^{\circ}C$ (Note 6) $T_A = +85^{\circ}C$ (Note 6) $T_A = +25^{\circ}C$ (Note 5) | ID | -0.67 -0.48 -0.53 | A |
| Pulsed Drain Current (Note 7) | | | IDM | 2.5 | A |

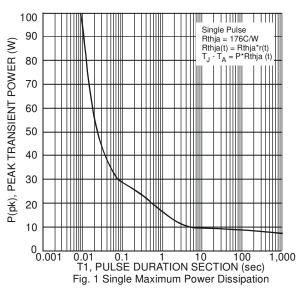
Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

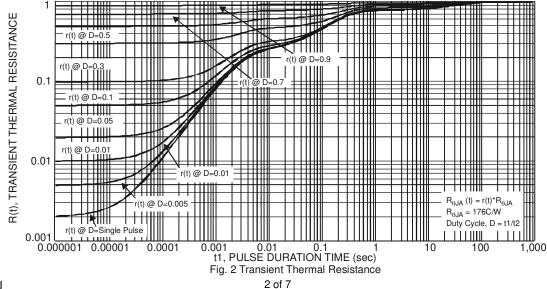
| Characteristic | Symbol | Value | Unit | |
|---|----------------------|------------------|------|------|
| Power Dissipation | (Note 5) | В | 0.45 | W |
| Power Dissipation | (Note 6) | PD | 0.71 | W |
| Thermal Resistance. Junction to Ambient | (Note 5) | P | 275 | °C/W |
| mermai Resistance, Junction to Ambient | (Note 6) | R _{θJA} | 177 | °C/W |
| Operating and Storage Temperature Range | TJ, T _{STG} | -55 to +150 | °C | |

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout

6. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.

7. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.





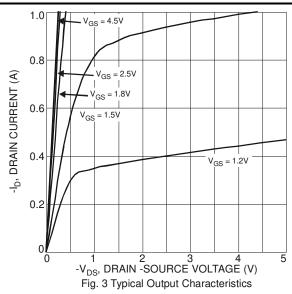


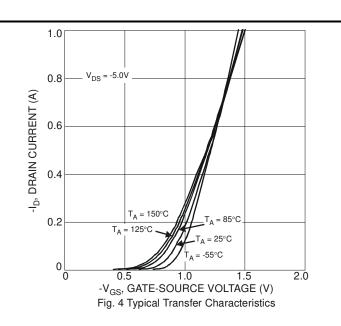
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|---|----------------------|------|------|------|------|---|--|
| OFF CHARACTERISTICS (Note 8) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -30 | — | _ | V | $V_{GS} = 0V, I_D = -250\mu A$ | |
| Zero Gate Voltage Drain Current T _J = 25°C | I _{DSS} | _ | — | -1 | μA | $V_{DS} = -30V, V_{GS} = 0V$ | |
| Gate-Source Leakage | IGSS | — | - | ±3 | μA | $V_{GS} = \pm 8V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 8) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -0.5 | — | -1.1 | V | $V_{DS} = V_{GS}, I_D = -250 \mu A$ | |
| | | | | 1 | | $V_{GS} = -4.5V, I_D = -400mA$ | |
| Static Drain-Source On-Resistance | R _{DS (ON)} | | - | 1.5 | Ω | $V_{GS} = -2.5V, I_D = -200mA$ | |
| | | | | 2 | | $V_{GS} = -1.8V, I_D = -100mA$ | |
| Forward Transfer Admittance | Y _{FS} | 50 | — | — | mS | $V_{DS} = -3V, I_D = -300mA$ | |
| Diode Forward Voltage | V _{SD} | _ | _ | -1.2 | V | $V_{GS} = 0V, I_{S} = -300mA$ | |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | | |
| Input Capacitance | C _{ISS} | _ | 76 | 150 | pF | | |
| Output Capacitance | Coss | — | 9 | — | pF | −V _{DS} = -15V, V _{GS} = 0V, −f = 1.0MHz | |
| Reverse Transfer Capacitance | C _{RSS} | — | 6.43 | — | pF | | |
| Gate Resistance | R _G | — | 167 | — | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge | Q _G | _ | 0.9 | — | nC | $V_{GS} = -4.5V, V_{DS} = -15V, I_{D} = -1A$ | |
| Total Gate Charge | Q _G | _ | 1.5 | — | nC | | |
| Gate-Source Charge | Q _{GS} | _ | 0.1 | — | nC | $-V_{GS} = -8V, V_{DS} = -15V,$ $-I_{D} = -1A$ | |
| Gate-Drain Charge | Q _{GD} | _ | 0.2 | — | nC | | |
| Turn-On Delay Time | t _{D(ON)} | — | 5.0 | — | ns | | |
| Turn-On Rise Time | t _R | — | 5.9 | — | ns | $V_{DD} = -10V, R_{L} = 10\Omega$ | |
| Turn-Off Delay Time | t _{D(OFF)} | — | 35.7 | — | ns | $V_{GS} = -4.5V, R_{G} = 6\Omega$ | |
| Turn-Off Fall Time | t _F | | 16.7 | — | ns | 1 | |

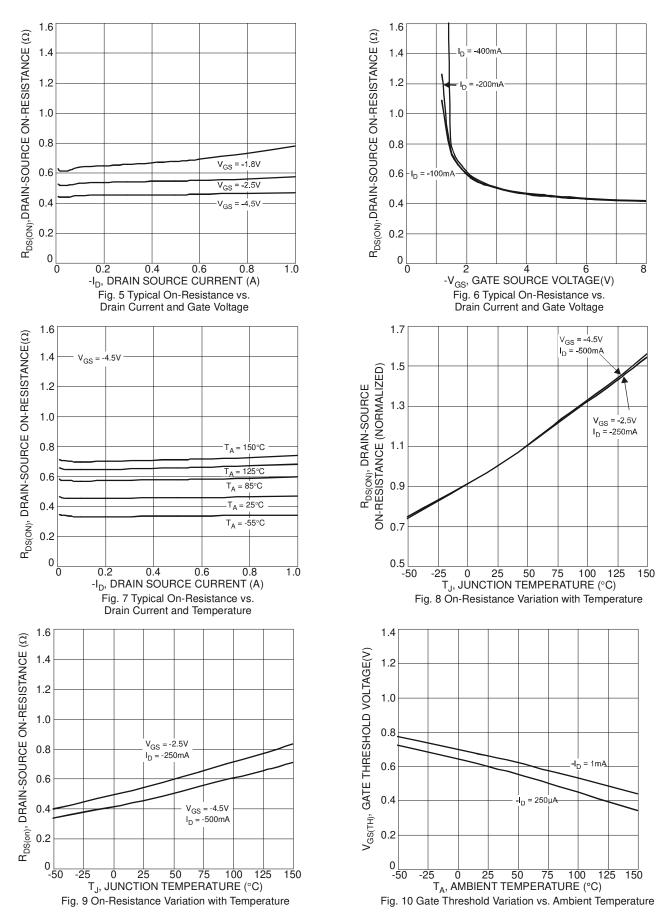
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing. Notes:

Typical Electrical Characteristics

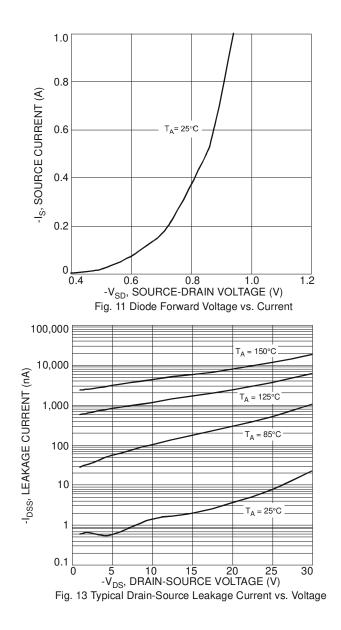


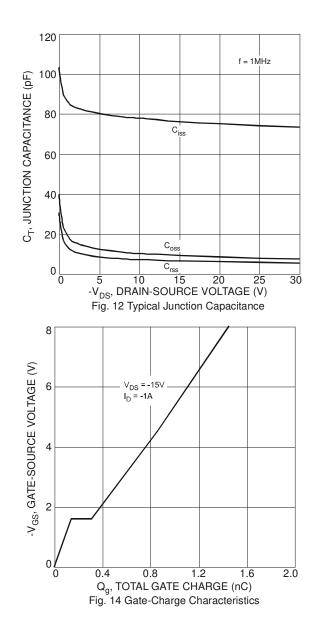








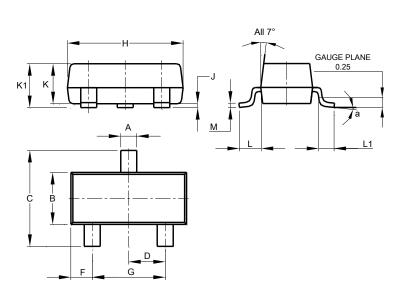






Package Outline Dimensions

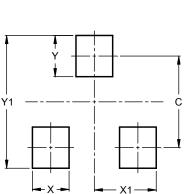
Please see http://www.diodes.com/package-outlines.html for the latest version.



| | SOT23 | | | | | | | |
|-----|--------|---------|-------|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | |
| Α | 0.37 | 0.51 | 0.40 | | | | | |
| В | 1.20 | 1.40 | 1.30 | | | | | |
| С | 2.30 | 2.50 | 2.40 | | | | | |
| D | 0.89 | 1.03 | 0.915 | | | | | |
| F | 0.45 | 0.60 | 0.535 | | | | | |
| G | 1.78 | 2.05 | 1.83 | | | | | |
| Н | 2.80 | 3.00 | 2.90 | | | | | |
| J | 0.013 | 0.10 | 0.05 | | | | | |
| K | 0.890 | 1.00 | 0.975 | | | | | |
| K1 | 0.903 | 1.10 | 1.025 | | | | | |
| 1 | 0.45 | 0.61 | 0.55 | | | | | |
| L1 | 0.25 | 0.55 | 0.40 | | | | | |
| М | 0.085 | 0.150 | 0.110 | | | | | |
| а | 0° | 8° | _ | | | | | |
| All | Dimens | ions in | mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.0 |
| Х | 0.8 |
| X1 | 1.35 |
| Y | 0.9 |
| Y1 | 2.9 |

SOT23

SOT23



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